

## Features

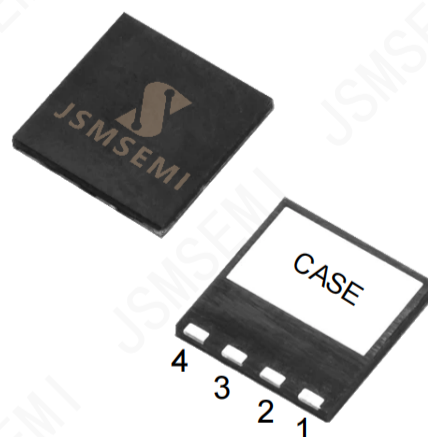
- Zero Forward/Reverse Recovery Current
- High Blocking Voltage
- High Frequency Operation
- Positive Temperature Coefficient on  $V_F$
- Temperature Independent Switching Behavior
- High surge current capability

## Benefits

- Higher System Efficiency
- Parallel Device Convenience without thermal runaway
- Higher Temperature Application
- No Switching loss
- Hard Switching & Higher Reliability
- Environmental Protection

## Applications

- PC Power
- Server Power Supply
- AC/DC converters
- DC/DC converters
- Uninterruptable power supplies



## Maximum Ratings ( $T_C=25^\circ\text{C}$ unless otherwise specified)

| Parameter                             | Symbol    | Test conditions                                                                                                                                                                            | Value           | Unit             |
|---------------------------------------|-----------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------|------------------|
| Peak Repetitive Reverse Voltage       | $V_{RRM}$ |                                                                                                                                                                                            | 650             | V                |
| Peak Reverse Surge Voltage            | $V_{RSM}$ |                                                                                                                                                                                            | 650             | V                |
| DC Blocking Voltage                   | $V_R$     |                                                                                                                                                                                            | 650             | V                |
| Continuous Forward Current            | $I_F$     | $T_C=25^\circ\text{C}$<br>$T_C=135^\circ\text{C}$<br>$T_C=140^\circ\text{C}$                                                                                                               | 28<br>11<br>10  | A                |
| Non repetitive Forward Surge Current  | $I_{FSM}$ | $T_C = 25^\circ\text{C}$ , $t_p=10$ ms,<br>Half Sine Pulse<br>$T_C = 110^\circ\text{C}$ , $t_p=10$ ms,<br>Half Sine Pulse<br>$T_C = 25^\circ\text{C}$ , $t_p=10$ $\mu\text{s}$ ,<br>Square | 50<br>40<br>300 | A                |
| Repetitive peak Forward Surge Current | $I_{FRM}$ | $T_C = 25^\circ\text{C}$ , $t_p=10$ ms,<br>Freq = 0.1Hz, 100 cycles,<br>Half Sine Pulse<br>$T_C = 110^\circ\text{C}$ , $t_p=10$ ms,<br>Freq = 0.1Hz, 100 cycles,<br>Half Sine Pulse        | 40<br>30        | A                |
| Total power dissipation               | $P_D$     | $T_C=25^\circ\text{C}$                                                                                                                                                                     | 83              | W                |
| Operating Junction Temperature        | $T_J$     |                                                                                                                                                                                            | -55 to 175      | $^\circ\text{C}$ |
| Storage Temperature                   | $T_{STG}$ |                                                                                                                                                                                            | -55 to 175      | $^\circ\text{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## Electrical Characteristics

| Parameter               | Symbol   | Test conditions                                | Min | Typ  | Max | Unit    |
|-------------------------|----------|------------------------------------------------|-----|------|-----|---------|
| DC Blocking Voltage     | $V_{DC}$ | $I_R = 250\mu A, T_J = 25^\circ C$             | 650 |      |     | V       |
| Forward Voltage         | $V_F$    | $I_F = 10A, T_J = 25^\circ C$                  |     | 1.5  | 1.8 | V       |
|                         |          | $I_F = 10A, T_J = 125^\circ C$                 |     | 1.65 |     |         |
|                         |          | $I_F = 10A, T_J = 175^\circ C$                 |     | 1.8  |     | V       |
| Reverse Current         | $I_R$    | $V_R = 650V, T_J = 25^\circ C$                 |     | 10   | 80  | $\mu A$ |
|                         |          | $V_R = 650V, T_J = 125^\circ C$                |     | 68   |     | $\mu A$ |
|                         |          | $V_R = 650V, T_J = 175^\circ C$                |     | 190  |     | $\mu A$ |
| Total Capacitive Charge | $Q_C$    | $V_R = 400V$<br>$T_J = 25^\circ C$             |     | 23   |     | nC      |
| Total Capacitance       | C        | $V_R = 1V, T_J = 25^\circ C,$<br>Freq = 1MHz   |     | 387  |     | pF      |
|                         |          | $V_R = 200V, T_J = 25^\circ C,$<br>Freq = 1MHz |     | 48   |     |         |
|                         |          | $V_R = 400V, T_J = 25^\circ C,$<br>Freq = 1MHz |     | 33   |     |         |

Note: This is a majority carrier diode, so there is no reverse recovery charge

## Thermal Characteristics

| Parameter          | Symbol        | Condition     | Min | Typ | Max | Unit         |
|--------------------|---------------|---------------|-----|-----|-----|--------------|
| Thermal Resistance | $R_{th(j-c)}$ | junction-case |     | 1.8 |     | $^\circ C/W$ |

## Ordering Information

| Order number  | Package    | Marking    | Operation Temperature Range | MSL Grade | Ship,Quantity | Green |
|---------------|------------|------------|-----------------------------|-----------|---------------|-------|
| SWNSC08650T6J | DFN8080-4L | SC6D10065Q | -55 to 175 $^\circ C$       | 1         | T&R,3000      | RoHS  |

## Typical Electrical Curves

Figure 1. Forward Characteristics

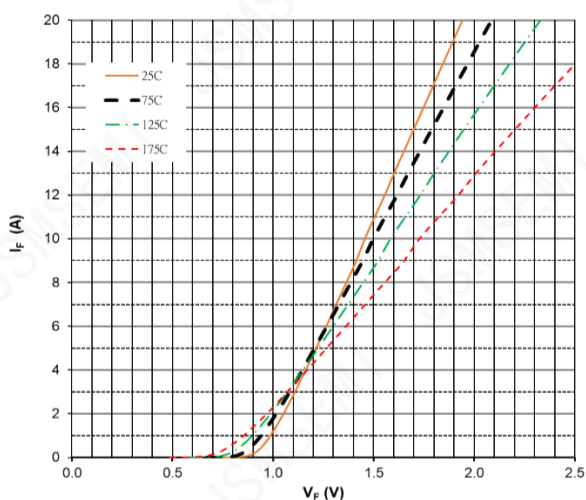


Figure 2. Forward Characteristics

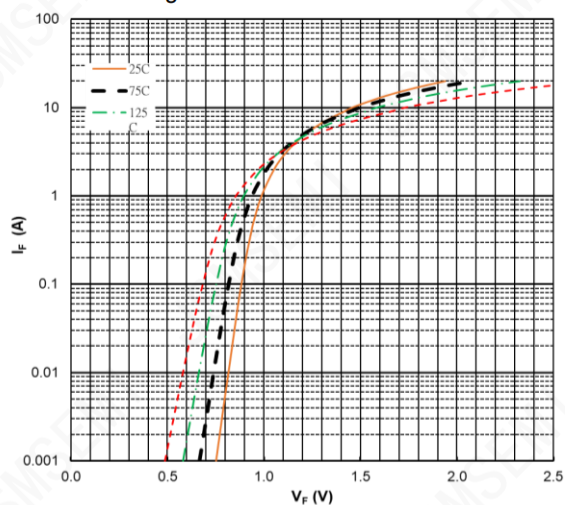


Figure 3. Reverse Characteristics

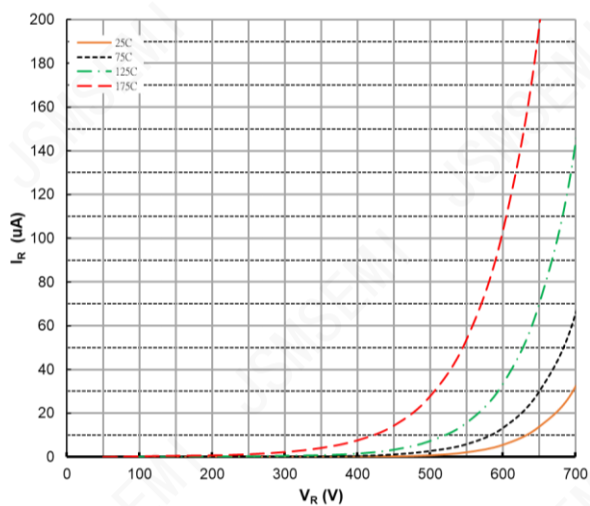


Figure 4. Power Derating

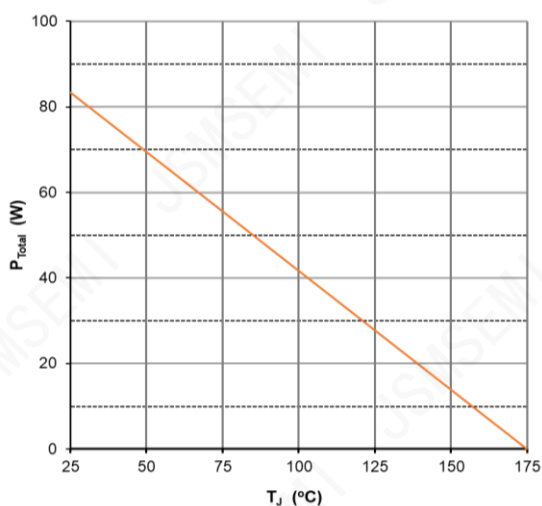


Figure 5. Capacitance vs Reverse Voltage

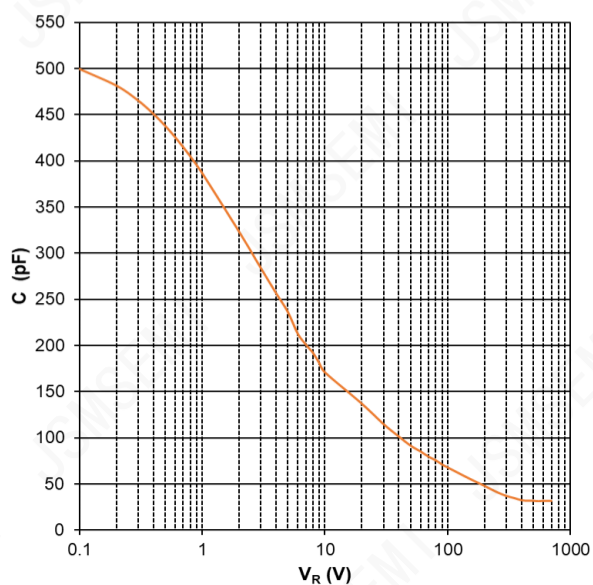
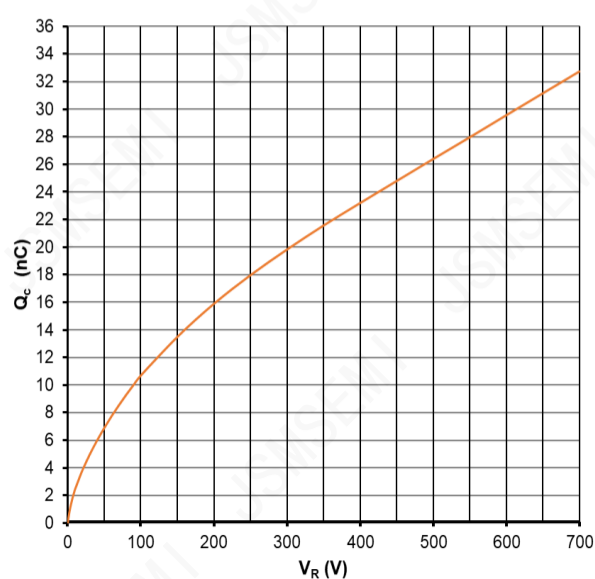
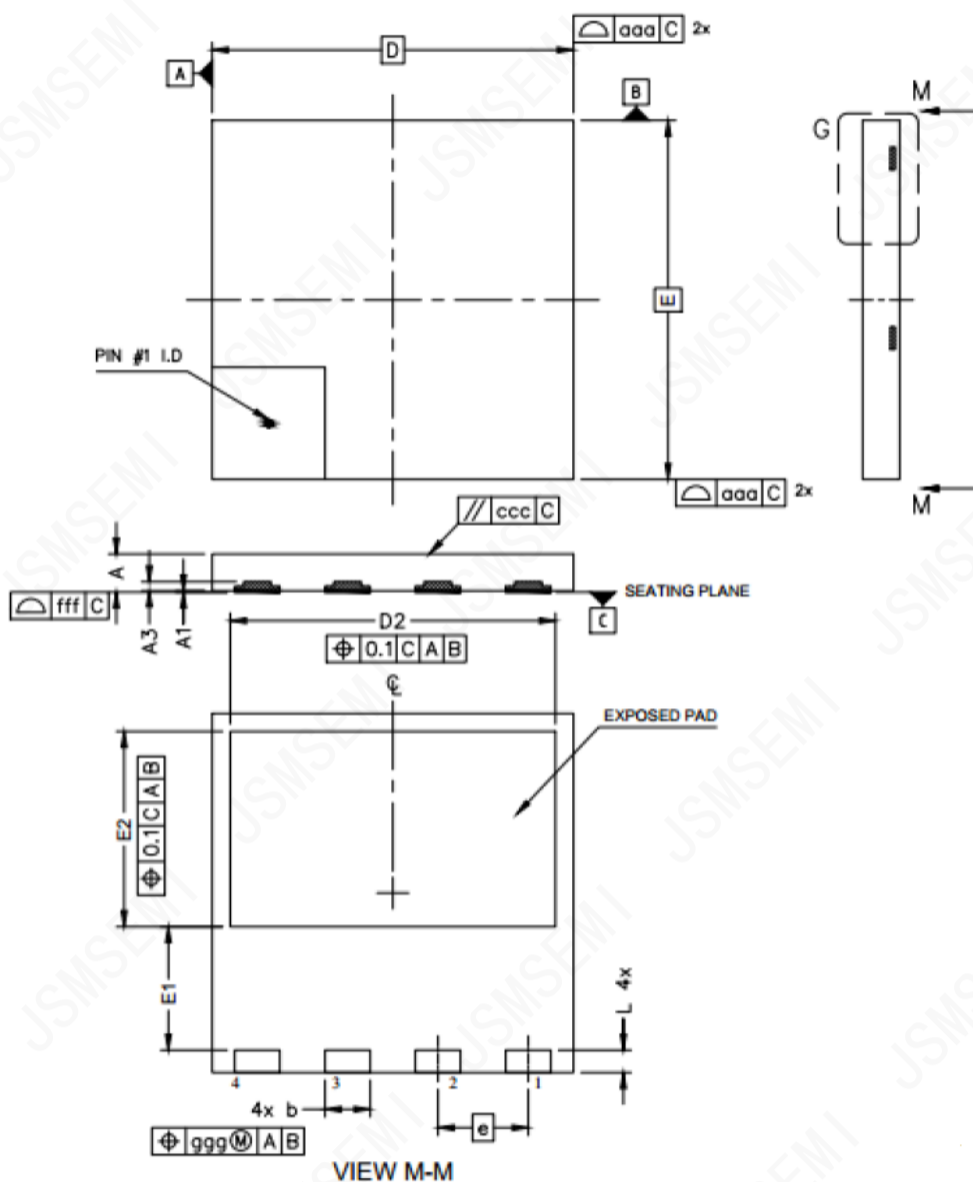


Figure 6. Recovery Charge vs Reverse Voltage



## Package Dimensions

(DFN 8x8 Package)



| Items | Millimeters |      |
|-------|-------------|------|
|       | Min         | Max  |
| A     | 0.75        | 0.95 |
| A1    | 0.00        | 0.05 |
| A3    | 0.10        | 0.30 |
| b     | 0.9         | 1.10 |
| D     | 7.90        | 8.10 |
| E     | 7.90        | 8.10 |
| D2    | 7.10        | 7.30 |
| E1    | 2.65        | 2.85 |
| E2    | 4.25        | 4.45 |
| e     | 2.00 (BSC)  |      |
| L     | 0.40        | 0.60 |
| aaa   | 0.10        |      |
| ggg   | 0.05        |      |
| ccc   | 0.05        |      |
| fff   | 0.05        |      |

## Revision History

| Rev. | Change          | Date      |
|------|-----------------|-----------|
| V1.0 | Initial version | 2/23/2022 |
|      |                 |           |

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